

Tailorable Acceptor $C_{60-n}B_n$ and Donor $C_{60-m}N_m$ Pairs for Molecular Electronics

Rui-Hua Xie,^{1,*} Garnett W. Bryant,¹ Jijun Zhao,² Vedene H. Smith, Jr.,³ Aldo Di Carlo,⁴ and Alessandro Pecchia⁴

¹Atomic Physics Division, National Institute of Standards and Technology, Gaithersburg, Maryland 20899-8423, USA

²Department of Physics and Astronomy, University of North Carolina at Chapel Hill, Chapel Hill, North Carolina 27599, USA

³Department of Chemistry, Queen's University, Kingston, ON K7L 3N6, Canada

⁴INFM-Dipartimento di Ingegneria Elettronica, Università di Roma "Tor Vergata," via del Politecnico 1, 00133 Roma, Italy

(Received 19 September 2002; published 23 May 2003)

Our first-principles calculations demonstrate that $C_{60-n}B_n$ and $C_{60-m}N_m$ can be engineered as the acceptors and donors, respectively, needed for molecular electronics by properly controlling the dopant number n and m in C_{60} . We show that acceptor $C_{48}B_{12}$ and donor $C_{48}N_{12}$ are promising components for molecular rectifiers, carbon nanotube-based n - p - n (p - n - p) transistors, and p - n junctions.

DOI: 10.1103/PhysRevLett.90.206602

PACS numbers: 72.80.Rj, 31.15.Ar, 33.15.-e, 85.65.+h

Modern microelectronics and computation are advancing at an extremely fast rate because of remarkable circuit miniaturization [1]. However, this trend will soon reach the scale of atoms or molecules. To continue toward faster and smaller computers, new schemes are required. Molecular electronics [2] is one such approach.

One major problem in molecular electronics is connecting the functional molecules and assigning the observed electrical properties in an unambiguous way to the molecules in question [3,4]. Fullerenes [5] are large enough to be identified by transmission electron microscopy or scanning probe methods [4], are stable and easy to build into molecular circuits [5,6], and might be inserted into single-walled carbon nanotubes (SWNT) [7]. Hence, fullerenes should be ideal components for molecular electronics.

As in semiconductor electronics [1], acceptor/donor pairs are critical for use in molecular electronics, for example, molecular rectifiers [2], nanoscale p - n - p transistors, and p - n junctions [8]. For traditional silicon doping, group V atoms act as donors and group III atoms are acceptors. Analogous acceptor/donor schemes are needed in molecular electronics [2]. Fullerenes are unique because they can be doped in several different ways (for example, endohedral [5], substitutional [5,9–11], and exohedral doping [5]). This should provide a wide range of possible acceptor/donor schemes.

To design active molecular devices, one needs components with controllable electronic properties [2,3]. For example, to obtain molecular rectification, the lowest unoccupied molecular orbital (LUMO) of the acceptor should lie at or above the Fermi level of the electrode and above the highest occupied molecular orbital (HOMO) of the donor. It is important to search for desired acceptor/donor pairs which satisfy this requirement. In this Letter, we suggest a controlled approach to obtain such pairs from C_{60} by using substitutional doping. Because the average carbon-carbon bond length in C_{60} is slightly larger than that in graphite, which can be substitutionally doped only by boron, and the force constants [5] are somewhat weakened by the curvature of the C_{60} surface,

both boron and nitrogen can substitute for one or more carbons in C_{60} [9–11]. Our first-principles calculations demonstrate that $C_{60-n}B_n$ and $C_{60-m}N_m$ can be engineered as the acceptors and donors, respectively, which are desired for molecular electronics by properly controlling the dopant number n and m . As an example, we present the electronic properties of the acceptor $C_{48}B_{12}$ and donor $C_{48}N_{12}$ and discuss their potential applications in molecular electronics.

First we discuss the electronic properties of $C_{60-n}B_n$, $C_{60-n}N_n$, and C_{60} to show that $C_{60-n}B_n$ and $C_{60-n}N_n$ can act as controlled dopants. The number n ranges from 1 to 12. Since there are many isomers [12] of $C_{60-n}X_n$ at fixed n , we take only the dopant assignment of Hultman *et al.* [11] as an example [13]. The optimized geometry and total energy are calculated by using the GAUSSIAN 98 program [14,15] with the B3LYP [16] hybrid density functional theory (DFT) [17] and 6-31G(d) basis set. The calculated results are summarized in Table I. The binding energy of $C_{60-n}X_n$ ($X = B, N$) decreases monotonically with increasing n . For $C_{60-n}B_n$, the binding energy is 0.21 to 0.38 eV/atom lower than that ($E_b = 6.98$ eV/atom) of C_{60} . For $C_{60-n}N_n$, it is 0.10 to 0.61 eV/atom lower than that of C_{60} . The stabilities of $C_{60-n}B_n$ and $C_{60-n}N_n$ are comparable to but less than that of C_{60} . In 1991, Smalley and co-workers [9] successfully synthesized $C_{60-n}B_n$ with $1 \leq n \leq 6$. In 1995, Hummelen *et al.* [10] produced $C_{59}N$. Recently, Hultman *et al.* [11] reported the existence of $C_{48}N_{12}$. These experiments show that certain stable $C_{60-n}X_n$ ($X = B, N$) can be made. Our results show that other B- or N-doped $C_{60-n}X_n$ structures for $n \leq 12$ have similar stability. Our calculated ionization potential ($E_I = 7.32$ eV) and electron affinity ($E_A = 2.40$ eV) for C_{60} agree well with experiments ($E_I = 7.54 \pm 0.01$ eV [18] and $E_A = 2.689 \pm 0.008$ eV [19]), indicating the accuracy of our calculations for $C_{60-n}X_n$. Among C_{60} and $C_{60-n}X_n$ at fixed n , $C_{60-n}B_n$ has the highest electron affinity, while $C_{60-n}N_n$ has the lowest ionization potential, indicating that $C_{60-n}B_n$ and $C_{60-n}N_n$ can serve as electron acceptor and donor, respectively.

TABLE I. LUMO (E_l , in eV), HOMO (E_h , in eV), binding energy (E_b , in eV/atom), ionization potential (E_I , in eV), and electron affinity (E_A , in eV) calculated for $C_{60-n}X_n$ ($X = B, N$) using B3LYP/6-31G(d).

n	$C_{60-n}B_n$					$C_{60-n}N_n$				
	E_l	E_h	E_b	E_I	E_A	E_l	E_h	E_b	E_I	E_A
1	-4.26	-5.57	6.77	6.77	3.07	-3.63	-4.72	6.88	5.93	2.15
2	-4.64	-5.25	6.75	6.35	3.53	-3.71	-4.64	6.82	5.85	2.27
3	-4.21	-5.49	6.74	6.37	3.32	-3.72	-4.69	6.78	5.92	2.29
4	-4.43	-5.60	6.73	6.79	3.32	-3.91	-4.56	6.73	5.83	2.19
5	-4.59	-5.54	6.71	6.85	3.56	-3.74	-4.56	6.69	5.95	2.20
6	-4.55	-5.49	6.70	7.01	2.98	-3.74	-4.61	6.64	5.85	2.32
7	-4.49	-5.54	6.67	6.75	3.23	-3.58	-4.59	6.60	5.91	2.39
8	-4.62	-5.34	6.66	6.44	3.50	-3.60	-4.41	6.55	5.65	2.36
9	-4.65	-5.43	6.64	6.61	3.34	-3.49	-4.45	6.51	5.77	1.90
10	-4.57	-5.44	6.63	6.57	3.45	-3.31	-4.28	6.46	5.52	1.89
11	-4.45	-5.61	6.62	6.87	3.30	-3.36	-4.35	6.41	5.71	2.29
12	-4.24	-5.58	6.60	6.73	3.08	-2.61	-4.38	6.37	5.66	1.49

Calculations of LUMO and HOMO energies are necessary to explore combinations of donors and acceptors suitable for molecular electronics. Table I shows the change of the LUMO/HOMO energies versus the dopant number n in the $C_{60-n}X_n$ molecule. Hence, acceptor/donor pairs which satisfy the required conditions in molecular electronics can be obtained by controlling the dopant number n and m in $C_{60-n}B_n$ and $C_{60-m}N_m$. For example, based on the acceptor LUMO and donor HOMO shown in Table I, we may choose acceptor/donor pairs, such as $C_{58}B_2/C_{58}N_2$, $C_{54}B_6/C_{54}N_6$, $C_{49}B_{11}/C_{51}N_9$, or $C_{48}B_{12}/C_{48}N_{12}$, to build molecular rectifiers exhibiting similar rectification behaviors. We take $C_{48}B_{12}/C_{48}N_{12}$ as one example to show their applications.

The molecular geometry (size) and symmetry play important roles in molecular electronics [2,3]. For example, an important factor in inducing rectification is some geometric asymmetry in the molecular junction [3]. C_{60} is a truncated icosahedron with perfect I_h symmetry. Changes in geometry (size) and symmetry of $C_{60-n}X_n$, due to the dopant-induced effects, are needed. Figure 1 shows the optimized structure of $C_{48}B_{12}$. For comparison, similar calculations were done for C_{60} and $C_{48}N_{12}$. The equilibrium $C_{48}B_{12}$, similar to $C_{48}N_{12}$ [11], has one B per pentagon and two B preferentially sitting in a hexagon. In $C_{48}X_{12}$ ($X = B, N$), the doping-induced distortion from the perfect C_{60} sphere is not localized to the neighborhood of each dopant but extends throughout the whole cage. The symmetry of $C_{48}B_{12}$ is the C_i point group, different from the S_6 symmetry for $C_{48}N_{12}$ [11]. This is due to their opposite electronic polarization, as discussed below. The molecular structure is examined by calculating the average distances (or radii R) from each atom to the center of the molecule. $C_{48}B_{12}$ has an ellipsoidal structure with ten unique sites labeled 1 to 10 in Fig. 1 and ten different radii ranging from 0.347 nm (site 2, 2') to 0.387 nm (site 8, 8'). In contrast, the ten unique radii

for $C_{48}N_{12}$ range from 0.340 nm (site 7) to 0.362 nm (site 5). For C_{60} , each carbon atom has an equal radius $R = 0.355$ nm, the same as that found in experiment [20]. Furthermore, we find 15 unique bonds (specified in Fig. 1) in $C_{48}B_{12}$: six boron-carbon bonds with lengths between 0.154 and 0.159 nm and nine carbon-carbon bonds with 0.139 to 0.150 nm lengths. In comparison, $C_{48}N_{12}$ has six nitrogen-carbon bonds with lengths ranging from 0.141 to 0.143 nm and nine carbon-carbon bonds with lengths from 0.139 to 0.145 nm. C_{60} , however, has one kind of single bond (0.145 nm) and one kind of double bond (0.139 nm), which are in excellent agreement with experiments [20].

To determine the electronic polarization, Mulliken charge analysis [21] was performed for the on-site charge Q_m of atoms in $C_{48}B_{12}$, $C_{48}N_{12}$, and C_{60} . $C_{48}B_{12}$ has two

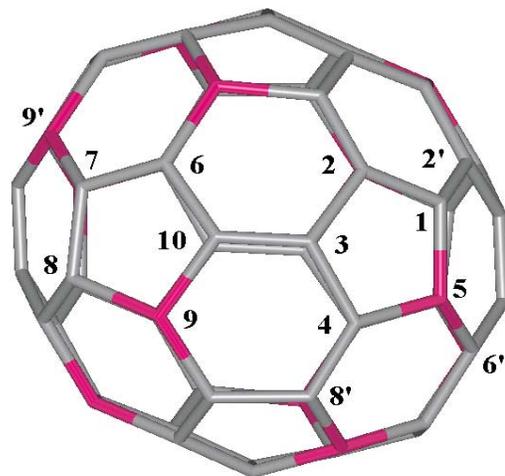


FIG. 1 (color online). $C_{48}B_{12}$ structure optimized with B3LYP/6-31G(d). Red (grey) is for B (C) sites. The 15 bonds between labeled vertices are all unique.

types of boron: one with $Q_m = 0.164|e|$ (site 5) and one with $Q_m = 0.187|e|$ (site 9), while carbon atoms in $C_{48}B_{12}$ have negative Q_m in the range from $-0.004|e|$ (site 3) to $-0.083|e|$ (site 8). In $C_{48}N_{12}$, there are two types of nitrogen: one with $Q_m = -0.595|e|$ (site 5) and one with $Q_m = -0.600|e|$ (site 9), and two types of C: one-fourth of the C atoms with negative Q_m ($-0.0125|e|$ at site 2 and $-0.0298|e|$ at site 3) and three-fourths of the carbon atoms with Q_m in the range of $0.192|e|$ (site 6) to $0.227|e|$ (site 4). In C_{60} , $Q_m = 0$ for each C. Hence, C_{60} is isotropic, while $C_{48}B_{12}$ and $C_{48}N_{12}$ have opposite electronic polarizations, leading to their different symmetries.

Applications of acceptors $C_{60-n}B_n$ and donors $C_{60-n}N_n$ require the proper lineup of energy levels. Upon B or N doping, the degeneracy of the original C_{60} levels, shown in Fig. 2, is removed by the structural distortion of the icosahedral symmetry. $C_{48}B_{12}$ ($C_{48}N_{12}$) is isoelectronic with C_{60}^{+12} (C_{60}^{-12}). Replacing 12 C atoms by 12 B atoms results in removing ten electrons from the HOMO (h_u symmetry, $E_h = -5.99$ eV) of C_{60} and two electrons from the second HOMO (g_g symmetry) of C_{60} . In contrast, replacing 12 C atoms by 12 N atoms leads to a complete filling of six electrons in the LUMO (t_{1u} symmetry, $E_l = -3.22$ eV) of C_{60} and six electrons in the second LUMO (t_{1g} symmetry) of C_{60} . Quantitatively, Fig. 2 shows the orbital energies of $C_{48}B_{12}$ and $C_{48}N_{12}$. They are different from each other because of the difference in valency of B and N atoms. For $C_{48}N_{12}$, the HOMO is a doubly degenerate level of a_g symmetry, while the LUMO is a nondegenerate level with a_u symmetry. For $C_{48}B_{12}$, the HOMO and LUMO are doubly degenerate levels of a_u and a_g symmetries, respectively. The $C_{48}B_{12}$ LUMO is just above the $C_{48}N_{12}$ HOMO and the approximate potential difference is about 1.63 eV. Thus, both

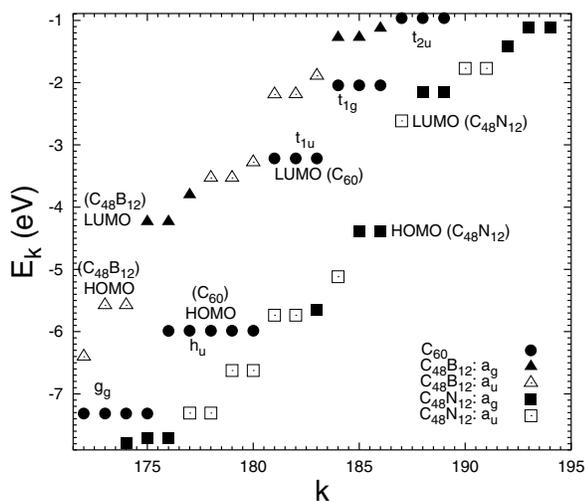


FIG. 2. Orbital energies E_k and symmetries of the k th eigenstate for $C_{48}X_{12}$ ($X = B, C, N$) calculated with B3LYP/6-31G(d).

$C_{48}B_{12}$ and $C_{48}N_{12}$ have the properties required for a proper rectifier behavior as demonstrated below.

Various experiments [22] have shown that individual molecules can act as molecular rectifiers [2]. The inset in Fig. 3(a) shows a rectifier molecule consisting of a donor $C_{48}N_{12}$ and an acceptor $C_{48}B_{12}$ connected by a tunneling bridge [a σ -electron system, $-(CH_2)_6-$]. The bridge forms a potential barrier that isolates the donor from the acceptor on the time scale of electron motion to or from the electrodes [2] (see review [6] about synthesis techniques of bridged C_{60} dimers through electroactive spacers). Following the Aviram-Ratner scheme [2], we expect that the electron current would pass from the cathode to the anode via acceptor, bridge, and donor. Since $C_{48}B_{12}$'s LUMO is -4.2 eV, we may choose metallic carbon nanotubes (work function $\phi \approx 5$ eV [23]), gold, silver, or copper ($\phi \approx 4.4, 4.7, 4.8$ eV, respectively [24]) as the electrodes. An initial B3LYP/3-21G calculation for the full, connected fullerene/spacer/fullerene system shows that the covalent bond between the spacer and doped fullerenes shifts the electronic structure of the doped fullerenes. However, the HOMO and LUMO of this system are still localized on the acceptor and donor sides, respectively, ensuring the desired rectifier behavior. The same properties hold for the acceptor/bridge/donor system [25]. Thus, a smaller threshold voltage for conduction is expected in one direction than in the other direction. As an example, we have investigated the rectifying characteristic of the $C_{48}B_{12}/C_6H_{14}/C_{48}N_{12}$ system by using nonequilibrium Green function theory in conjunction with a DFT-based tight-binding model [26,27]. The rectifier molecule is connected to gold contacts that we treat in the s -wave approximation with a constant density of states near the Fermi level [28]. The calculated current/applied potential characteristic is shown in Fig. 3(a). A typical rectification characteristic is obtained with a turn-on bias close to the energy difference between the $C_{48}B_{12}$ LUMO and the $C_{48}N_{12}$ HOMO. Recently, Joachim *et al.* [4] have observed the electrical current flowing through an individual C_{60} molecule with a scanning tunneling microscope (STM). In light of this progress and the calculated size of $C_{48}X_{12}$ ($X = N, B$), our rectifier molecule also should be identifiable by STM.

Heterojunctions for molecular electronics can also be formed using $C_{60-n}X_n$ donors and acceptors. Hybrid nanostructures formed by filling a SWNT with C_{60} [7] were observed and can be superconducting [7] or metallic [29]. Our DFT calculations, done within the local density approximation with double numerical basis including d -polarization function [15,30], show that the incorporation of the $C_{48}B_{12}$ or $C_{48}N_{12}$ into a (10, 10) or (17, 0) [5] SWNT is energetically favorable. About 2.4 eV binding energy per molecule is gained after $C_{48}B_{12}$ or $C_{48}N_{12}$ is inserted periodically inside the SWNTs. In our calculations of doped SWNTs with a one-dimensional periodic boundary condition along the tube axis, three unit cells of

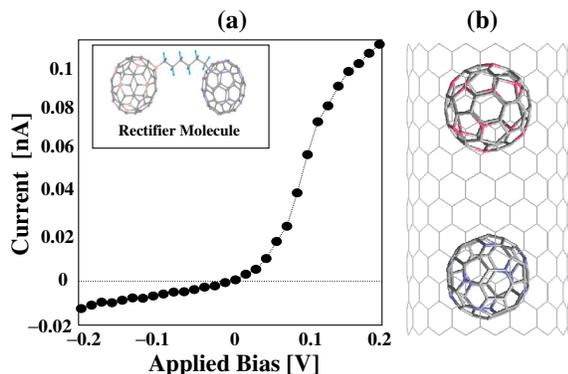


FIG. 3 (color online). (a) Calculated current through a rectifier molecule (inset) which consists of $C_{48}B_{12}$ (left, red for B atoms) and $C_{48}N_{12}$ (right, blue for N atoms) connected by C_6H_{14} (middle, green for H atoms) and is coupled to two Au electrodes via S atoms on the two sides. The two C atoms in the ends of the C_6H_{14} bridge are connected to the N (B) atoms in $C_{48}N_{12}$ ($C_{48}B_{12}$), respectively. A B3LYP/3-21G calculation shows that the connected rectifier molecular superstructure is stable relative to the separated, individual components by about 19.545 kcal/mol energy. (b) A prototype for $C_{48}X_{12}@ (17, 0)$ SWNT-based ($X = B, N$) p - n junction.

a (10, 10) tube or two unit cells of a (17, 0) tube are included in the supercell with one $C_{48}B_{12}$ or $C_{48}N_{12}$. Charge analysis found that placing an acceptor $C_{48}B_{12}$ into a (17, 0) tube puts a $+0.67|e|$ charge on the SWNT, while incorporating a donor $C_{48}N_{12}$ into a (17, 0) SWNT puts a $-0.39|e|$ charge on the SWNT. Similar results are obtained for a (10, 10) SWNT. Hence, putting $C_{48}B_{12}$ into a semiconducting tube results in a p -type region on the SWNT, while putting donors $C_{48}N_{12}$ into a semiconducting tube leads to a n -type region on the SWNT. Thus, it is possible to use them to get n - p - n and p - n - p transistors. As shown in Fig. 3(b), doping a (17, 0) semiconducting SWNT with $C_{48}B_{12}$ and $C_{48}N_{12}$ should make a SWNT-based p - n junction.

In conclusion, we show that acceptor $C_{60-n}B_n$ and donor $C_{60-m}N_m$ pairs needed for molecular electronics can be obtained by properly controlling n and m . We demonstrated the rectifying characteristic of a molecular rectifier built from our engineered acceptor/donor pairs. Heterojunctions for molecular electronics can be made by inserting these dopants into semiconducting carbon nanotubes. Efficiently synthesizing those acceptor/donor pairs would be of great experimental interest within reach of today's technology. Very recently, small nitrogen doped fullerenes have been reported [31], showing experimental progress in this direction.

V. H. S. gratefully acknowledges support from NSERC. A. D. C. acknowledges support from the European DIODE Network and the Italian MURST-CNR under the project "Nanoelectronics." R. H. X. thanks M. A. Ratner for comments and the HPCVL at Queen's

University for the use of its parallel supercomputing facilities.

*Email address: rhxie@nist.gov

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